

#### A Hard X-Ray Free-Electron Laser Oscillator at the European XFEL facility

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XFEL

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## Why do we need it?



## XFELO←What's that?









## The X-ray Free Electron Laser Oscillator (XFELO)







## The <u>X-ray</u> Free Electron Laser Oscillator (XFELO)





Patrick Rauer - XFELO @ EuXFEL



# Why Now?



- XFELO necessities:
  - High enough single pass gain to compensate for losses
  - →Brilliant electron beam (Linac)
  - Matching between electron bunch repitition and photon pulse circumference rate
    - F.E. LCLS : el. rep-rate = 120 Hz↔2500 km optical path length
- → euXFEL: el. rep-rate ~ 4.5 MHz $\leftrightarrow$ 66 **m** optical path length!





## X-RAFEL (non-idealized)

- Issues regarding the realization of an XFELO:
  - High mechanical and optical demands
    - $\rightarrow$  Time- and positional overlap of el-bunch and X-ray pulse after one circumference
    - $\rightarrow$  From resonator theory  $\rightarrow \Delta z_{mirror} \approx 10 \mu m; \Delta \theta_{mirror} \approx 12 n rad$
    - → Intermediate Gain Oscillator →  $\Delta \theta_{\text{mirror}} \approx 100-200$ nrad ✓
  - Realistic electron bunch (energy chirp, emissitivies,...)



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## Simulation including mirror tilt and el. jitter







## Simulation including mirror tilt and el. jitter





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# XFELO $\rightarrow$ Heatload Issues

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• Saturated XFELO  $\rightarrow$  6mJ at >1MHz rep.rate on crystal

 $\rightarrow$  Disturbing optical stability  $\leftarrow$  (long term) vibrations

 $\rightarrow$  Disturbing crystal spectral reflectivity

 Thermal expansion of the lattice in the region of interest:



Implemented in Simulations

 Dynamics Answer Of Crystal **Towards Rapid Expansion** slnd  $\rightarrow$  Strain Waves (Ultrasonics):



- Influence unknown todate  $\rightarrow$  checked by simulation as well as by experiment [I.Bahns]
- $\rightarrow$  Not yet implemented





# Heatload $\rightarrow$ Pile-up of heating



- Heatload leads to strong temperature rise in crystal
- Beat in crystal temperature
- Beat also apparent in XFELO-energy
- Different heating of crystals  $\rightarrow$  Shift of res. wavelength with respect to each other





## Future Plans at EuXFEL

 Implement a proof-of-principle XFELO at the end of the SASE1 tunnel (last 4-6 Undulators)



tunability, two(four) thick mirrors, compliant with standard operation)

## **NOT AN APPROVED PROJECT**







## Conclusion

- European XFEL ideal source for implementing an XFELO
- Mechanical tolerances are state of art
- Problems:
  - Outcoupling (keeping longitudinal coherence)
  - Heatload  $\leftarrow$  Stability at saturation
- Need to try it out  $\rightarrow$  Proof of principle experiment

## Thank you for listening





## Heatload $\rightarrow$ Pile-up of heating





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## Laser-crystal interaction in detail



- Pulsed Laser irradiation of diamond crystals lead to a stacking temperature increase → thermal expansion → shift of Bragg conditions
- $\rightarrow$  importance of cooling
- → necessity of considering nanoscale effects (like boundary scattering)
- $\leftarrow$  Included in model by reduced anisotropic thermal conductivity





#### Nanoscale heat transport - Boundary scattering -

Heat source At low temperatures the mean free path Phonons of the heat carriers increases Profile of a heated crystal  $\rightarrow$  Phonons can reach the crystal boundaries without scattering  $t_{cr}$  $\rightarrow$  At boundaries can be reflected specularly (no influence on direction paraliei to surface), diffusively (boundaries act like point defects), or inelastic → Conditions generally unknown: Necessity Bulk mean free of experimental measurement! path of the crystal

• Currently evaluation based on work of A. Majumdar (1993) assuming diffusive boundaries:

$$\lambda_{eff}(T) = \lambda(T) \cdot \left(\frac{4^{l_{mfp}}}{3 t_{cr}} + 1\right)^{-1}$$





#### Nanoscale heat transport - Gradient effect -

- Heat source (temperature curvature)  $\uparrow T$  on same scale as  $l_{mfp}$  of carriers:
- → **Franker**'s/*lawa* spen, ±*i*/*NCB* to a seed noth (failser) (120:137-20070xi) nlatioD: low  $\Delta r$  D(er /diff) as io 21 gov at the end second for right for state and second bectwee at taneo  $\tau \frac{\delta q}{\delta t} + q = -\lambda \nabla T$  for than sign to yait to account the postilistic effections and the posting domes of the optilistic for the posting domes of the posting domes of the optilistic for the posting domes of the posting domes of

# → First experiments by C.Maag confirm assumptions in 1D



Profile of a heated crystal







#### XFELO – configurations

#### • <u>Two Bragg-mirrors, two focussing elements</u>



Four Bragg-mirrors, one focussing element







## Some Symantics: XFELO vs. RAFEL

#### X<u>FELO</u>

- Low gain device ( $\mathcal{G}\ll 1$ )
- Saturation after some hundreds of roundtrips
  → Very stable output
- Principally upgradable to phase locked resonator
- Low gain ← Very sensitive to all forms of distortions

#### (X-)RAFEL

- Intermediate to high gain device  $(\mathcal{G} \ge 1)$  to  $\mathcal{G} \gg 1$ )
- Saturation after from 5 to some tens of roundtrips
- Less sensitive to distortions than XFELO
- Output more dependent on electron beam properties + fluctuations
- Much more stable than SASE due to powerful seed





#### X-ray Free Electron Laser Oscillator (idealized)







## Simulation including mirror tilt and el. jitter



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## XFELO width realistic e-bunch

• Electron distribution from start to end simulations [1]



- Electron distribution (500pC) at beginning of SASE1 Undulator
  - Pronounced energy chirp
  - → May be problematic for XFELO due to very small *seeding* bandwidth

[1] Igor Zagorodnov, http://www.desy.de/fel-beam/s2e/xfel/Nominal/nom500pC.html







# Thank you for listening





